

Symbol Parameter Ratings Units Drain to Source Voltage 250 V V_{DS} Gate to Source Voltage ±20 V V_{GS} Drain Current -Continuous (Silicon limited) T_C = 25°C 14 T_A = 25°C -Continuous (Note 1a) 2.8 I_D А -Pulsed 30 Power Dissipation T_C = 25°C 78 PD W T_A = 25°C 2.5 **Power Dissipation** (Note 1a) Operating and Storage Junction Temperature Range -55 to +150 °C T_J, T_{STG}

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.6	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1	a) 50	0/10

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS2734	FDMS2734	Power 56	13"	12mm	3000 units

March 2011

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General Description

UltraFET devices combine characteristics that enable benchmark efficiency in power conversion applications. Optimized for $r_{DS(on)}$, low ESR, low total and Miller gate charge, these devices are ideal for high frequency DC to DC converters.

4 G

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S



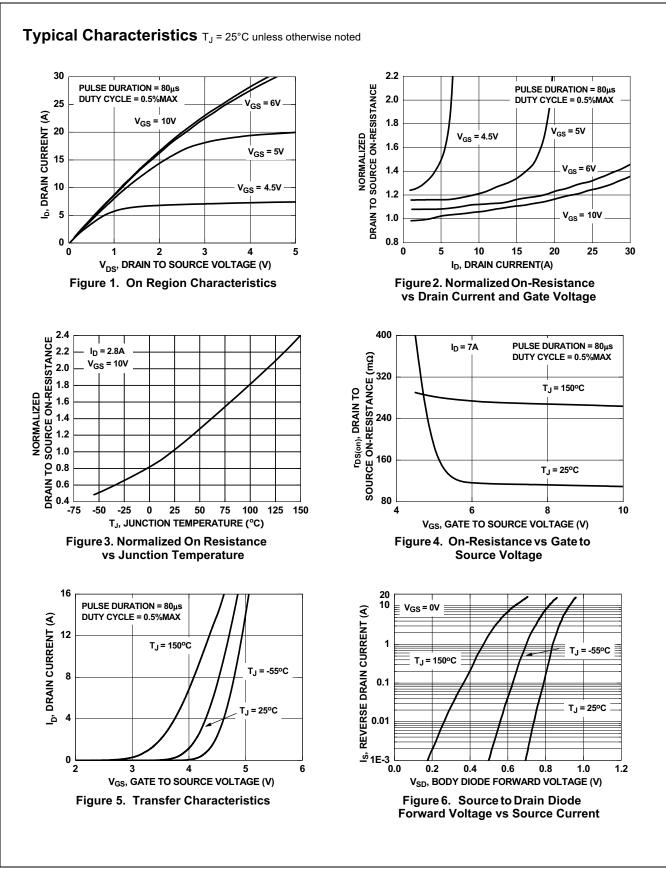
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- Max $r_{DS(on)}$ = 122m Ω at V_{GS} = 10V, I_D = 2.8A
- Max $r_{DS(on)}$ = 130m Ω at V_{GS} = 6V, I_D = 1.7A
- Low Miller Charge
- Optimized efficiency at high frequencies
- RoHS Compliant

FDMS2734
N-Channel UI
UltraFET Tren
Trench®
MOSFET

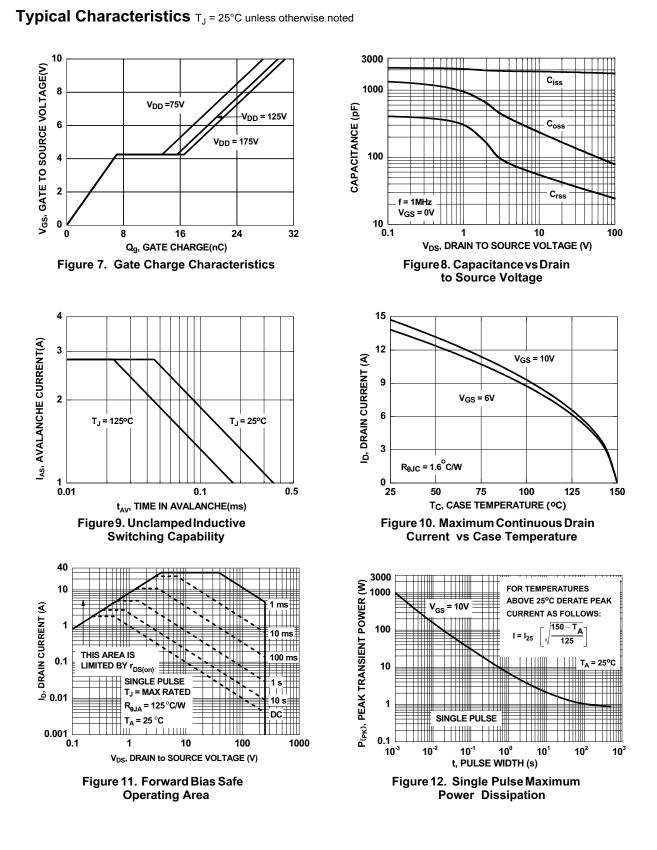
	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	250			V
ΔBV_{DSS}	Breakdown Voltage Temperature			250		mV/°C
ΔT _J	Coefficient Zero Gate Voltage Drain Current				1	A
I _{DSS}	e e e e e e e e e e e e e e e e e e e	$V_{DS} = 200V,$ $V_{GS} = \pm 20V, V_{GS} = 0V$			±100	μA
IGSS	Gate to Source Leakage Current	v _{GS} - ±200, v _{GS} - 00			100	nA
On Chara	cteristics (Note 2)					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2	3	4	V
$\frac{\Delta V_{\text{GS(th)}}}{\Delta T_{\text{J}}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to $25^{\circ}C$		-11		mV/°C
		V _{GS} = 10V, I _D = 2.8A		105	122	
r _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 6V, I_D = 1.7A$		110	130	mΩ
		$V_{GS} = 10V, I_D = 2.8A T_J = 125^{\circ}C$		217	258	1
9fs	Forward Transconductance	$V_{DS} = 10V, I_D = 2.8A$		11		S
	Characteristics	- · · · · · · · · · · · · · · · · · · ·				
-				1775	2365	рĘ
C _{iss}	Input Capacitance Output Capacitance	V _{DS} = 100V, V _{GS} = 0V,		80	110	pF
C _{oss}		f = 1MHz		25		pF
C _{rss}	Reverse Transfer Capacitance Gate Resistance	f = 1MHz		0.9	40	pF
R _g		1 - 1101112		0.5		Ω
Switching	Characteristics				I	
t _{d(on)}	Turn-On Delay Time	V _{DD} = 125V, I _D = 2.8A		22	36	ns
t _r	Rise Time	$V_{DD} = 123V, I_D = 2.6A$ - $V_{GS} = 10V, R_{GEN} = 6\Omega$		10	20	ns
t _{d(off)}	Turn-Off Delay Time			36	58	ns
t _f	Fall Time			12	22	ns
Q _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0V \text{ to } 10V V_{DD} = 125V$		30	42	nC
Q _{gs}	Gate to Source Gate Charge	I _D = 2.8A		7		nC
Q _{gd}	Gate to Drain "Miller" Charge			9		nC
Drain-Soເ	urce Diode Characteristics					
V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0V, I _S = 2.8A (Note 2)		0.75	1.20	V
	Reverse Recovery Time	I _F = 2.8A, di/dt = 100A/μs		79	119	ns
t _{rr}	-	L = 2.8A dt/dt = 100A/us				



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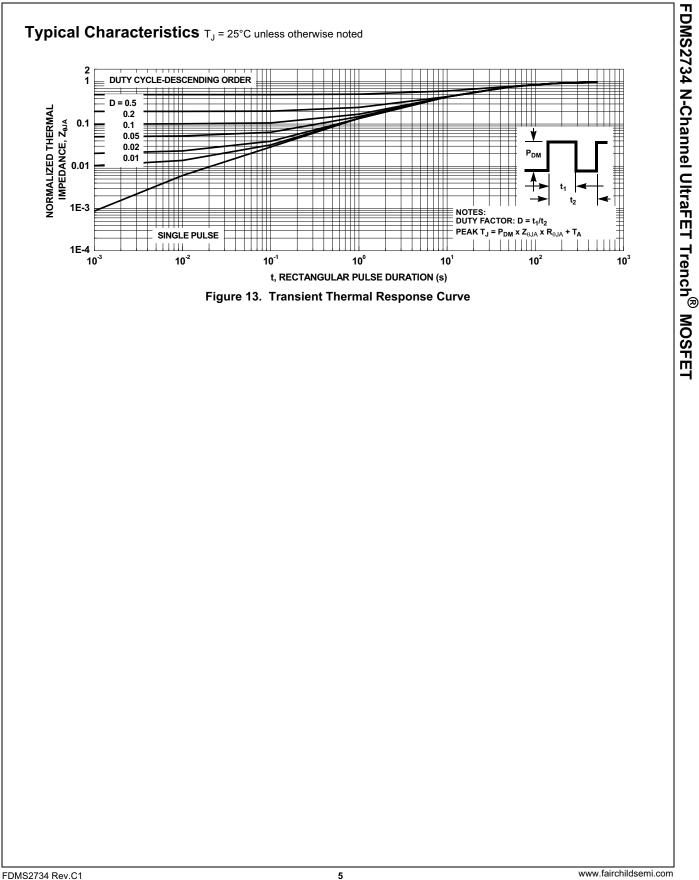


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FDMS2734 N-Channel UltraFET Trench[®] MOSFET



___0.10 C 2X F 5.0 A -0.77 Ð 8 5 4.52 6.0 6.61 4.32 3.91-0.10 C 4 2X PIN #1 IDENT -1 TOP VIEW 0.61 TYP. 1.27 TYP -0.8 MAX RECOMMENDED LAND PATTERN // 0.10 C (0.25)___ 0.08 C Ċ 0.05 SIDE VIEW SEATING PLANE 3.86 🙆 3.66 0.64 0.44 З PIN #1 IDENT (OPTIONAL) 3.42 3.22 4.01? .10 5 1.27 0.36-0.46 🚯 ⊕ 0.10 M C A B 3.81
(A) ⊕ 0.05⊛ C BOTTOM VIEW NOTES: ODES NOT FULLY CONFORM TO JEDEC REGISTRATION, MO-229. DATED 11/2001. B. DIMENSIONS ARE IN MILLIMETERS. C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994 D. TERMINALS 5,6,7 AND 8 ARE TIED TO THE EXPOSED PADDLE MLP08GrevD

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